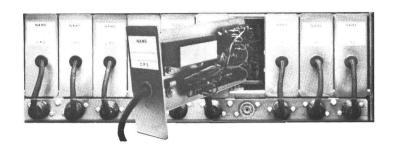


MASTR Progress Line

SHARED REPEATER PANEL (OPTIONS 7645 & 7646)



SPECIFICATIONS

Tone Frequencies

71.9 to 203.5 Hz

Tone Frequency Stability

±0.2%

Decoder Response (threshold bandwidth)

 $3\% \pm 0.5\%$ of Tone Frequency

Audio Response

300 to 3000 Hz

Temperature Range

-30 °C to +60 °C (-22 °F to +140 °F)

Option No.	Description	Used With
7645	Tone Panel 19D402486-G1	MASTR Professional Progress Line Repeater Station
7646	Tone Module 19D402608-G1 and Tone Network 19B205280-G1 thru -G34	Tone Panel Option 7645

*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

TABLE OF CONTENTS

SPECIFICATIONS Cover	r
DESCRIPTION	1
SYSTEM OPERATION	1
	2
Tone Module and Tone Frequency Network	2 3 4
MODIFICATIONS	4
	5
Troubleshooting Procedure	7
INTERCONNECTION DIAGRAM	8
OUTLINE AND SCHEMATIC DIAGRAM (Tone Controlled Switch and 10-Volt Regulator A705)	9
OUTLINE AND SCHEMATIC DIAGRAM (Tone Module)	1
OUTLINE DIAGRAM (Tone Panel) 14	4
SCHEMATIC DIAGRAM (Tone Panel) 1	5
INSTALLATION DIAGRAM (Modification Kit 19B216215-G1)	7
PARTS LIST	
Tone Controlled Switch/10-Volt Regulator	2
ILLUSTRATIONS	
Figure 2 - Low-Pass Filter/Amplifier Block Diagram Figure 3 - Tone Gate/Tone Module Block Diagram Figure 4 - Amplifier/Tone Gate Hold Block Diagram Figure 5 - Tone Module Block Diagram	1 2 2 3 4 4 5

--- WARNING ---

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

DESCRIPTION

The General Electric Shared Repeater is a Channel Guard Repeater Station combination capable of providing repeater service for up to 10 different users (or fleets) sharing the same radio frequency. The Shared Repeater provides each user with a separate Channel Guard tone frequency, permitting him to hear only those calls from other units in his own system.

Encoder/Decoder modules are used to identify the tone frequency of each RF modulated signal -- and to re-transmit the message to the user's mobiles. Normally, the first signal received will be decoded and re-transmitted before the next message is received. In some instances, however, a stronger signal may override a signal that is already in the process of being re-transmitted by the station.

SYSTEM OPERATION

A signal received from a mobile unit by the repeater station is fed into the control panel audio coupler and the tone panel low-pass filter (Figure 1).

The low-pass filter eliminates voice frequencies and feeds the Channel Guard tone frequencies into the tone modules containing the tone frequency networks FL601 thru FL610. A tone coded signal that matches one of the tone frequency networks will activate Tone Controlled switch A705 to trigger the carrier-operated switch or relay and key the transmitter.

Tone from the frequency matching network is also fed into the transmitter to modulate the RF signal. The tone/voice-

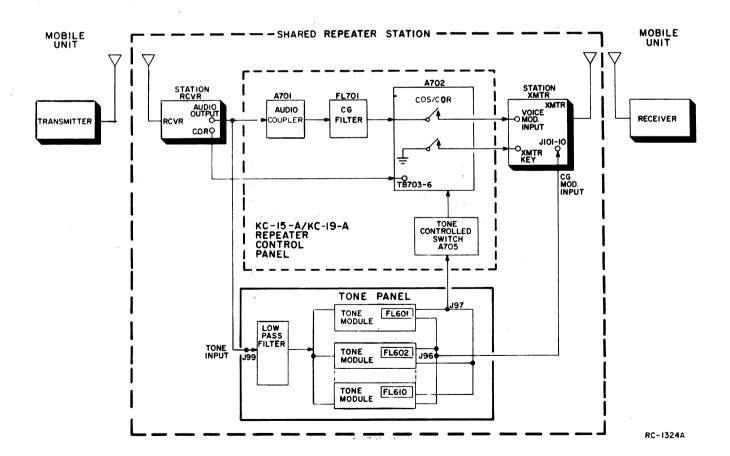


Figure 1 - Shared Repeater Block Diagram

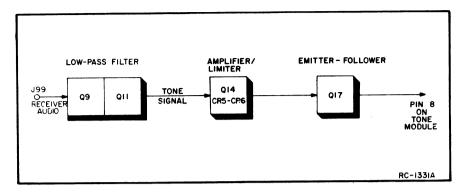


Figure 2 - Low-Pass Filter/Amplifier Block Diagram

modulated signal is then received by the user's Channel Guard mobile receiver.

Signals received by the Repeater Station that are not modulated by one of the station Channel Guard frequencies will be attenuated by the tone frequency networks (FL601-FL610).

CIRCUIT ANALYSIS

TONE PANEL

The Tone Panel circuit board contains the tone gate, low-pass filter, amplifiers, tone gate hold circuits, and provisions for inserting up to 10-slide-in Tone Modules. Each tone module contains a tone frequency network operating at a Channel Guard frequency within the 71.9 to 203.5 Hz range.

Low-Pass Filter

Audio from the station receiver is fed to a low-pass filter on the Tone Panel. The filter blocks the voice frequency signals and allows the Channel Guard tones to pass (Figure 2).

Amplifier and Emitter-Follower

Tones from the low-pass filter are

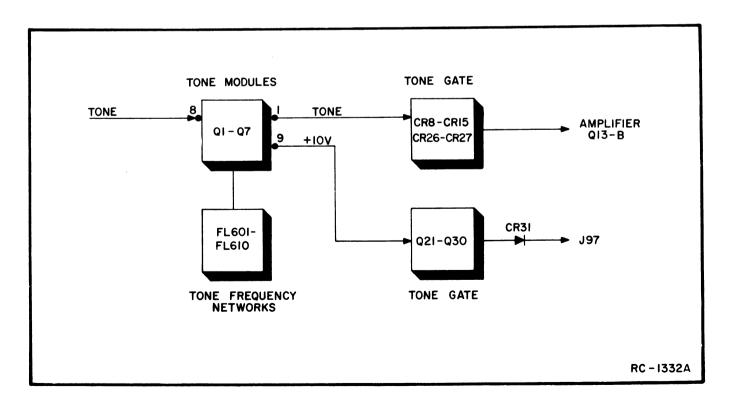


Figure 3 - Tone Gate/Tone Module Block Diagram

coupled through C20 to the base of amplifier Q14. Signals are limited by diodes CR5 and CR6, and fed to the base of emitter-follower Q17. Following Q17, the signals are coupled to pin 8 of each Tone Module to drive the frequency networks.

Tone Gate

The +10 volts from a tone module will fire only 1 of the tone gate transistors (Q21-Q30) located on the Tone Panel.

The resulting positive voltage (+10 volts) at the emitter of Q21 (for example) will then produce a voltage drop across R65 to turn on CR8, allowing the output of the tone module to pass through C28 and R75 to the base of amplifier Q13. The +10 volts at the emitter of Q21 is coupled through diodes CR16 and CR31 to activate Tone Controlled Switch A705 (Figure 3).

Amplifiers

The tone signal from the operating tone gate stage is amplified by Q13 and Q1 with de-emphasis provided by R2, C1, C3 and R10. The amplified output signal at J96 will produce a constant transmitter deviation at all transmitting frequencies.

NOTE -

If the station transmitter contains an Integrated Circuit Oscillator Module (ICOM), amplifier Ql and the de-emphasis circuits are by passed. See RC-1624.

Tone Gate Hold

Transistors Q18 and Q19 form a one-shot multivibrator timing circuit to keep the tone path from module to transmitter open during sudden fades or tone drop-outs. Assume, for example, that tone module with FL601 is functioning and diode CR8 is turned on by tone gate Q21. If the tone input to FL601 momentarily disappears, the DC voltage at tone module pin 9 will drop back to low value, cutting Q31 OFF. A negative-going edge at C45 will momentarily bias the base of Q18 negative through diode CR32, causing the collector voltage at Q18 to rise toward +10 volts, as Q18 turns off.

The positive voltage at the collector of Q18 turns Q20 ON, and the positive voltage produced at Q20 emitter feeds thru R129 and CR38 to keep tone gate diode CR8 on for the duration of the Q18-Q19 timing cycle. The positive voltage to the Tone Controlled Switch (at J97) is maintained during this interval by the decay time constant of C46 with R111, and the input impedance of the Tone Controlled Switch.

TONE MODULE AND FREQUENCY NETWORK

Tone signals from the Tone Panel are fed to the base of amplifier Q1. The audio signal from the amplifier is fed to the base of common-emitter amplifier Q2, providing a 180° phase shift through R3, R2 and C1 for the positive feedback necessary to provide high gain in Q1-Q2.

Negative feedback is provided through the Tone Frequency Network from the collector to the base of Q1 at all frequencies, except at the tone network frequency. Q1

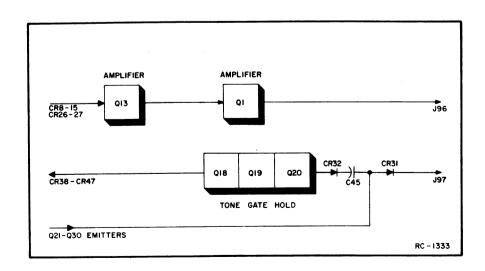


Figure 4 - Amplifier/Tone Gate Hold Block Diagram

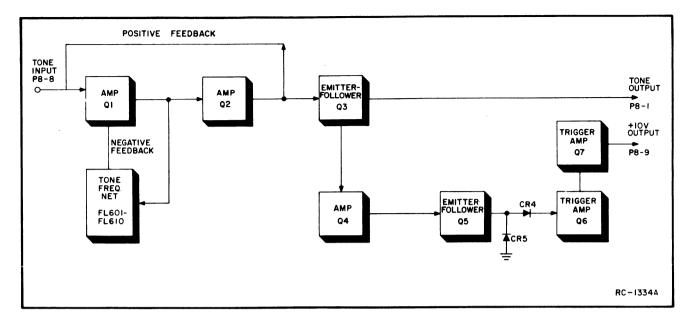


Figure 5 - Tone Module Block Diagram

will amplify only at the network frequency. The positive feedback from Cl increases the gain of Q1-Q2. Protection against noise falsing is provided by the incoming noise signal to Q1. (Figure 5).

The tone output from emitter follower Q3 is fed to the tone gate stage on the Tone Panel and to the base of amplifier Q4. Amplified by Q4, the signal is isolated from the CR4-CR5 detector circuit by emitter-follower Q5. When the DC potential is above the threshold level of trigger circuit Q6-Q7, Q6 will turn ON and Q7 will turn OFF, thereby producing a +10 volt output. The Q8 circuit is used in Remote operations only.

TONE CONTROLLED SWITCH/10-VOLT REGULATOR (part of Repeater Control Panel)

Tone Controlled Switch/10-Volt Regulator is mounted on the Repeater Control Panel (KC-15-A/KC-19-A) directly behind the audio coupler unit on the component wiring side of the panel.

Tone Controlled Switch

The Tone Controlled Switch will operate only when a greater than +6 volt signal is fed into it from the tone gate stage of the Tone Panel. The voltage input turns on Q3 to activate the carrier-operated switch or relay, keying the transmitter. Zener diode VR2 prevents Q3 from turning on until the proper operating voltage is received from the Tone Panel.

10-Volt Regulator

The regulator supplies a regulated +10 volts to the Tone Panel, Tone Modules, and the Tone Frequency Networks. The regulator is supplied by a +13 regulated voltage taken from the EP-38-A Power Supply.

Resistor Rl provides the base bias to turn Ql on. Zener diode VRl provides a voltage reference for the regulator. R3, R4 and R5 form a voltage divider that can be varied by potentiometer R5 to adjust the base voltage of Q2, thereby adjusting the output voltage exactly to +10 volts.

MODIFICATIONS

The station transmitter, power supply and control panel are modified for Shared Repeater Operation. If the station transmitter is equipped with an Integrated Circuit Oscillator Module (ICOM), the tone panel is also modified.

Power Supply

A two-conductor shielded cable (7134854-P5) has been connected between P101 and TB501 as shown in Figure 6 to couple tone through power supply to the transmitter input.



Figure 6 - Power Supply Tone Cable Connections

Transmitter

The Transmitter Exciter has been modified as in Channel Guard applications. A two-conductor shielded cable (19B205478-G1) has been connected from terminals 10 and 15 of J101 to J7 and J8 on the Exciter Board as shown in Figure 7. This cable couples the tone signal to the transmitter tone modulator circuit.

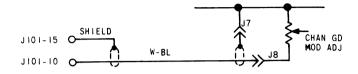


Figure 7 - Transmitter Tone Cable Connections

Repeater Control Panel (4KC15A10 or 4KC19A10)

- Tone Controlled Switch A705 (19C303974-G1) has been installed and connected as shown on the Outline and Schematic Diagram on page 8.
- The jumper between TB703-1 and -4 (on KC-15-A) or the jumper between TB703-1 and -3 (on KC-19-A) has been removed.

Tone Panel 19D402486-G1

When the station transmitter is equipped with an ICOM Module, A601 on the tone panel contains a 19B216215-G1 Modification Kit. The modification produces the flat audio response required for modulating an ICOM equipped transmitter. Installation Diagram RC-1624 describes the modification and provides a tone panel circuit diagram showing the modification kit installed.

MAINTENANCE

The Transmitter, Receiver and Power Supply are essentially standard and servicing should be performed according to the standard techniques outlined in the unit Maintenance Manuals. The Tone Controlled Switch/10-Volt Regulator is mounted on the KC-15-A Repeater Control Panel, otherwise the panel servicing is identical to the prescribed procedures in the unit Maintenance Manual.

TONE OUTPUT LEVELS

The tone levels applied to the transmitter modulator (measured at J85 on the tone panel) are shown in the following chart. These levels are used for transmitters without Integrated Circuit Oscillator Modules (ICOM's). When the transmitter is equipped with an ICOM, the tone panel is modified according to RC-1624 to provide a flat output (approximately 1 volt) at J85 over the entire range of tone frequencies.

Tone Frequency	Minimum Output At J85*
71.9 Hz	1.0 V
74.4 Hz	0.95 V
77.0 Hz	0.9 V
79.7 Hz	0.86 V
82.5 Hz	0.8 V
85.4 Hz	0.76 V
88.5 Hz	0.71 V
91.5 Hz	0.68 V
94.8 Hz	0.66 V
97.4 Hz	0.61 V
100.0 Hz	0.6 V
103.5 Hz	0.57 V
107.2 Hz	0.54 V
110.9 Hz	0.5 V
114.8 Hz	0.47 V
118.8 Hz	0.44 V
123.0 Hz	0.42 V
127.3 Hz	0.38 V
131.8 Hz	0.36 V
136.5 Hz	0.33 V
141.3 Hz	0.31 V
146.2 Hz	0.29 V
151.4 Hz	0.27 V
156.7 Hz	0.26 V
162.2 Hz	0.24 V
167.9 Hz	0.22 V
173.8 Hz	0.2 V
179.9 Hz	0.19 V
186.2 Hz	0.18 V
192.8 Hz	0.17 V
203.5 Hz	0.15 V
* In Volts, measu	red with AC-VTVM

TROUBLESHOOTING

Troubleshooting and servicing those units that are unique to the Shared Repeater Station are described in the following Troubleshooting Procedure Chart.

			•
			•
			į

TROUBLESHOOTING PROCEDURE

SYMPTOM	CHECK THE FOLLOWING:
One individual mobile cannot operate Repeater Station. All other mobiles on same frequency OK.	Mobile transmitter for proper Channel Guard frequency and tone deviation.
One fleet of mobiles (with a common Channel	I - TONE MODULE AND TONE FREQUENCY NETWORK
Guard frequency) can- not operate Repeater. Other fleets (with	a. That tone frequency network corresponds to proper Channel Guard tone frequency.
other fleets (with other Channel Guard frequencies) OK.	b. For tone of proper frequency at pin 8 and amplified tone at pin 1 of tone module.
	c. For approximately 2VDC (no tone) and 10 VDC (with tone) at pin 9.
	d. If tone appears at pin 1, but no DC at pin 9, check Q5, Q6 and Q7.
	e. If tone or DC voltage do not appear, check Q1, Q2, and Q3.
	f. Substitute a replacement network, if necessary.
·	g. If tone and DC are both OK, go to Step II.
	II TONE PANEL
	a. For tone at Q13-B and +DCV at TB703-3 of Control Panel (KC-15-A) or TB703-5 (KC-19-A) with the tone applied.
	b. Tone gate stage (Q21-30) and associated diodes, if no tone is measured in Step II-a.
Repeater is keyed by	a. Tone amplifiers Ql3 and Ql.
mobiles, but does not re-transmit any tones.	b. Cabling to transmitter PlO1-10.
	c. Modulator circuit of transmitter.
No mobiles can key transmitters.	a. For voltage swing of 0 to +1.5-2VDC at TB703-6 on Repeater Control Panel. Also audio should be heard from test speaker when mobile comes on. If not, check receiver.
	b. If receiver is OK, jumper TB703-4 to TB703-1 (on KC-15-A) or TB703-3 to TB703-1 (on KC-19-A). When mobile is received, transmitter should key and be voice modulated (but not necessarily tone modulated). If not, check COS/COR, 5-second delay, 3-minute timer, and transmitter keying circuits.
	c. If transmitter operates as in Step b above with jumper, then measure voltage at TB703-3 (KC-15-A) or TB703-5 (KC-19-A). If voltage swings from approximately 1VDC to 6VDC or more with tone signal applied, the trouble is in Tone Controlled Switch (A705) Q3.
	If voltage does not swing up, to Step d.
	d. For a tone signal at pin 8 of all tone modules with a mobile signal being received. If no signal is present, trace signal through stages Q9, Q11, Q14, and Q17.

- 1. CABLES SHOULD BE CONSTRUCTED IN ACCORDANCE WITH WIRING INSTRUCTIONS A4031623.
- 2. ALL WIRES ARE #16 AWG. EXCEPT: WIRES #46,47,49,50,51, & 52 ARE #22SJ. TERMINATE WIRES AS FOLLOWS:

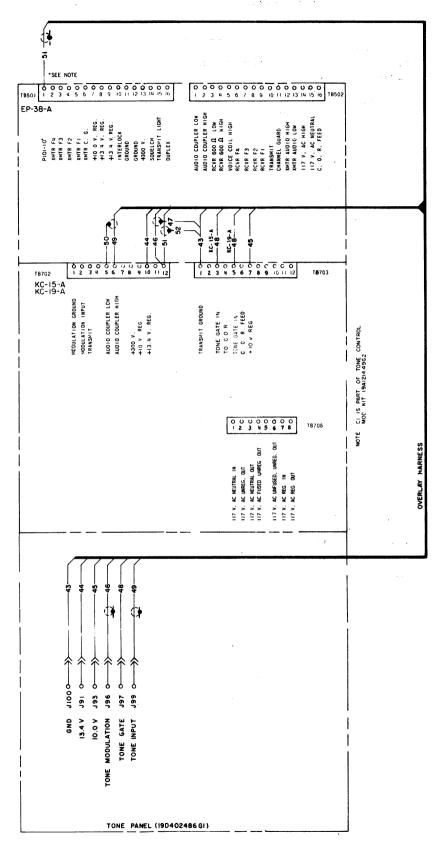
TO KC-19-A TERMINAL A7147264P1 44,45, 8 48 WITH A714764P1 46, 49,50,51 WITH 37491625P1 45,52,847706ETHER WITH 198209260P101 TERMINATE WIRE NO.S 46,47,49,50,51, 8 52 PER A7136250. WIRE#

TO EP-38-A TO TONE PANEL TERMINAL 43,44,45,46,48, 8 49 WITH A4029840P3

TERMINAL

- 3. MARK WIRES IN CABLE ON BOTH ENDS WITH CORRESPOND-ING WIRE NUMBER USING MARKER STRIP 198209090.
- 4. CABLE SHOULD BE CONSTRUCTED IN SUCH A WAY AS TO ALLOW ENOUGH SLACK TO PERMIT MOUNTING A 3.5"
 OPTION PANEL BETWEEN EP-38-A AND KC-19-A AND A 3.5" OPTION PANEL BETWEEN KC-19-A AND TONE PANEL .

*NOTE ON EP38A12 REMOVE **18 O-W WIRE FROM TB501-1.
CUT END OFF AND TAPE. TIE BACK IN HARNESS.

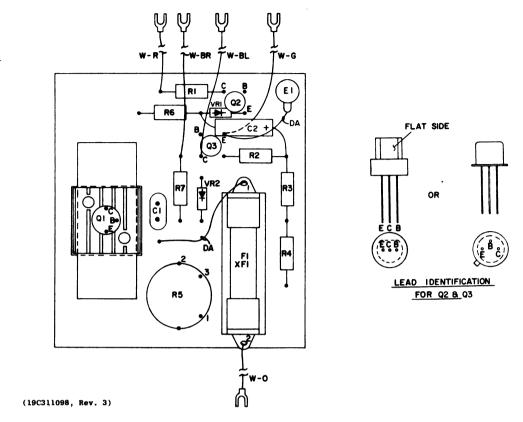




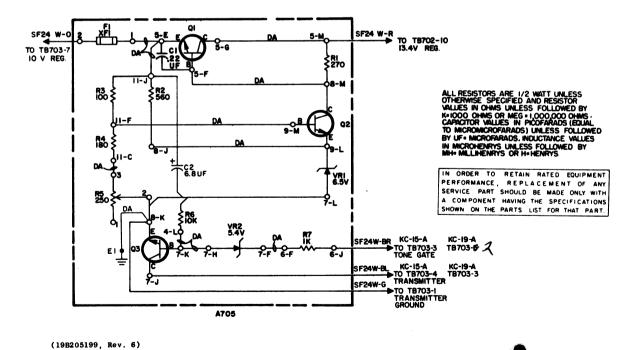
INTERCONNECTION DIAGRAM

SHARED REPEATER

TONE CONTROL SWITCH (A705)



SCHEMATIC DIAGRAM



OUTLINE & SCHEMATIC DIAGRAM

TONE CONTROLLED SWITCH & 10-VOLT REGULATOR 19C303974G1

PARTS LIST

LBI-3689B

TONE CONTROLLED SWITCH AND 10 V REGULATOR 19C303974G1 A705

SYMBOL	GE PART NO.	DESCRIPTION
Cl	19B209243P9	Polyester: 0.22 µf ±20%, 50 VDCW.
C2*	5496267P18	Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague Type 150D. Added by REV A.
E1*	40368 35P4	Terminal; sim to Shakeproof 2177-04-000. Added by REV B.
F1	7487942P2	Slow blowing: 3/8 amp at 250 v; sim to Bussmann MDL-3/8.
1		TRANSISTORS
Q1	19A115300P1	Silicon, NPN; sim to Type 2N3053.
Q2 and Q3	19A115123P1	Silicon, NPN; sim to Type 2N2712.
		RESISTORS
Rl	3R77P271J	Composition: 270 ohms ±5%, 1/2 w.
R2	3R77P561J	Composition: 560 ohms ±5%, 1/2 w.
R3	3R77P101J	Composition: 100 ohms ±5%, 1/2 w.
R4	3R77P181J	Composition: 180 ohms ±5%, 1/2 w.
R5	19B209113P1	Variable, wirewound: 250 ohms ±20%, 2.5 w.
R6	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.
R7	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.
		VOLTAGE REGULATORS
VRl	4036887P6	Silicon, Zener.
VR 2	4036887P5	Silicon, Zener.
		SOCKETS
XF1	7141008P1	Fuseholder: 5 amps at 125 v; sim to Littelfuse E-357001.
		MISCELLANEOUS
	19A122048P1	Heat sink, (Used with Q1),
1		
1		
	1	
	1	
<u> </u>	L	HETER OR CHANGER BY PRODUCTION CHANGES

^{*}COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

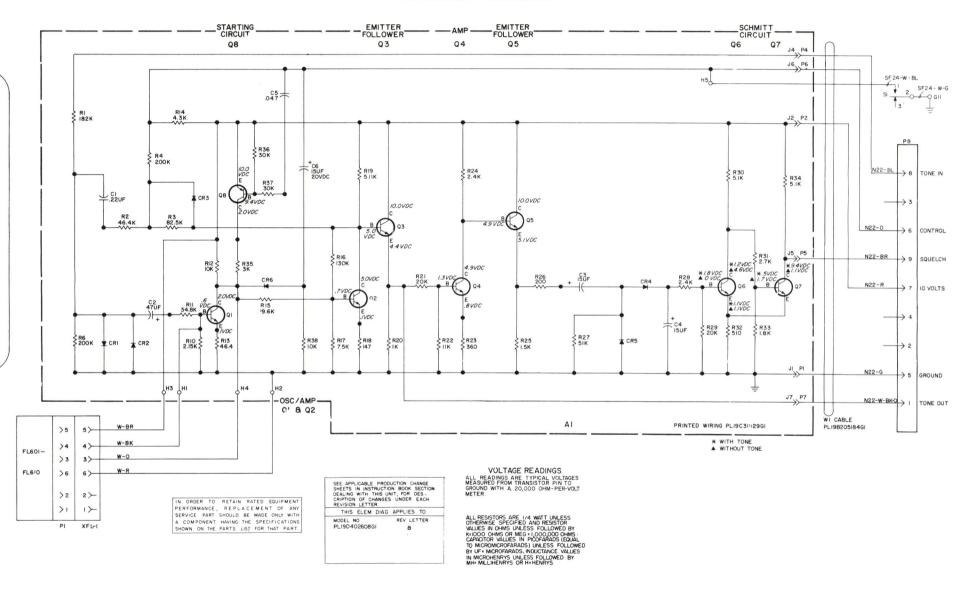
PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A To eliminate voltage transients on 10-volt line when transmitter is unkeyed, preventing false operation of Tone Switch. Added C2.
- REV. B To eliminate voltage transients which cause the transmitter to key when the channel guard tone is removed from the RF signal. Added ground connection, El, to the emitter of Q3.

OUTLINE DIAGRAM NAME FLI XFLI TEST (19D402825, Rev. 1) (19C311120, Sh. 1, Rev. 1) (19C311120, Sh. 2, Rev. 1) FLAT SIDE -- RUNS ON SOLDER SIDE RUNS ON BOTH SIDES SECTION A-A - RUNS ON COMPONENT SIDE FOR QI THRU Q8

SCHEMATIC DIAGRAM



(19D402762, Rev. 3)

SCHEMATIC & OUTLINE DIAGRAM

TONE MODULE & TONE FREQUENCY NETWORK 19D402608G1

PARTS LIST

LBI-3700C

TONE MODULE 19D402608G1

SYMBOL	GE PART NO.	DESCRIPTION
A1*		COMPONENT BOARD 19C311129G1 (Added by REV A)
Cl	19A116080P109	Polyester: 0.22 µf ±10%, 50 VDCW.
C2	5496267P2	Tantalum: 47 μ f $\pm 20\%$, 6 VDCW; sim to Sprague Type 150D.
C3 and C4	5496267P14	Tantalum: 15 µf ±20%, 20 VDCW; sim to Sprague Type 150D.
C5	19A115028P111	Polyester: .047 µf ±20%, 200 VDCW.
C6	5496267P14	Tantalum: 15 μf $\pm 20\%$, 20 VDCW; sim to Sprague Type 150D.
	:	DIODES AND RECTIFIERS
CR1 and CR2	5494922P1	Silicon; sim to Type 1N456.
CR3 thru CR6	19A115250P1	Silicon.
CRO		
J1 and J2	4033513P15	Contact, electrical: sim to Bead Chain R40-1A.
J4 thru J7	4033513P15	Contact, electrical: sim to Bead Chain R40-1A.
		TRANSISTORS
Q1 and Q2	19A115362P1	Silicon, NPN; sim to Type 2N2925.
Q3	19A115123P1	Silicon, NPN; sim to Type 2N2712.
Q4	19A115362P1	Silicon, NPN; sim to Type 2N2925.
Q5 thru Q7	19A115123P1	Silicon, NPN; sim to Type 2N2712.
Q8	19A115768P1	Silicon, PNP; sim to Type 2N3702.
		RESISTORS
R1	5495948P426	Deposited carbon: 182,000 ohms ±1%, 1/2 w; sim to Texas Instrument Type CD1/2MR.
R2	5495948P365	Deposited carbon: 46,400 ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument Type CD1/2MR.
R3	5495948P389	Deposited carbon: 82,500 ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument Type CD1/2MR.
R4	3R152P204J	Composition: 0.2 megohm ±5%, 1/4 w.
R6	3R152P204J	Composition: 0.2 megohm ±5%, 1/4 w.
R10	19A116278P233	Metal film: 2150 ohms ±2%, 1/2 w.
R11	19A116278P353	Metal film: 34,800 ohms ±2%, 1/2 w.
R12	19A116278P301	Metal film: 10,000 ohms ±2%, 1/2 w.
R13	19A116278P65	Metal film: 46.4 ohms ±2%, 1/2 w.
R14	3R152P432J	Composition: 4300 ohms ±5%, 1/4 w.
R15	19A116278P329	Metal film: 19,600 ohms ±2%, 1/2 w.
R16	19A116278P412	Metal film: 130,000 ohms ±2%, 1/2 w.
R17 R18	19A116278P285 19A116278P117	Metal film: 7500 ohms ±2%, 1/2 w. Metal film: 147 ohms ±2%, 1/2 w.

CVMPO	CE DADT NO	DESCRIPTION	CVMARO	OF DART NO	DECEDIDATION
SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
R19	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.	R5	5495948P438	Deposited carbon: 243,000 ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument Type CD1/2MR.
R20 R21	3R152P102J 3R152P203J	Composition: 1000 ohms ±5%, 1/4 w. Composition: 20,000 ohms ±5%, 1/4 w.	R6	5495948P430	Deposited carbon: 200,000 ohms ±1%, 1/2 w; sim
R22	3R152P113J	Composition: 11,000 ohms ±5%, 1/4 w.	R10	5495948P233	to Texas Instrument Type CD1/2MR. Deposited carbon: 2150 ohms ±1%, 1/2 w; sim to
R23	3R152P361J	Composition: 360 ohms ±5%, 1/4 w.		0.000.00	Texas Instrument Type CD1/2MR.
R24	3R152P242J	Composition: 2400 ohms ±5%, 1/4 w.	R11	5495948P353	Deposited carbon: $34,800$ ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument Type CD1/2MR.
R25	3R152P152J	Composition: 1500 ohms ±5%, 1/4 w.	R12	5495948P301	Deposited carbon: $10,000$ ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument Type CDI/2MR.
R26	3R152P201J	Composition: 200 ohms ±5%, 1/4 w.	R13	5495948P65	Deposited carbon: 46.4 ohms $\pm 1\%$, $1/2$ w; sim to
R27 R28	3R152P513J 3R152P242J	Composition: 51,000 ohms ±5%, 1/4 w. Composition: 2400 ohms ±5%, 1/4 w.			Texas Instrument Type CD1/2MR.
R29	3R152P203J	Composition: 20,000 ohms ±5%, 1/4 w.	R14	3R77P432J	Composition: 4300 ohms ±5%, 1/2 w.
R30	3R152P512J	Composition: 5100 ohms ±5%, 1/4 w.	R15	5495948P329	Deposited carbon: 19,600 ohms ±1%, 1/2 w; sim to Texas Instrument Type CD1/2MR.
R31	3R152P272J	Composition: 2700 ohms ±5%, 1/4 w.	R16	5495948P412	Deposited carbon: 130,000 ohms ±1%, 1/2 w; sim to Texas Instrument Type CD1/2MR.
R32	3R152P511J	Composition: 510 ohms ±5%, 1/4 w.	R17	5495948P285	Deposited carbon: 7500 ohms ±1%, 1/2 w; sim to
R33	3R152P182J	Composition: 1800 ohms ±5%, 1/4 w.	n10	E405049D117	Texas Instrument Type CD1/2MR.
R34	3R152P512J	Composition: 5100 ohms ±5%, 1/4 w.	R18	5495948P117	Deposited carbon: 147 ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument Type CD1/2MR.
R35 R36	3R152P302J 3R152P303J	Composition: 30 000 ohms ±5%, 1/4 w.	R19	5495948P269	Deposited carbon: 5110 ohms $\pm 1\%$, 1/2 w; sim to Texas Instrument Type CD1/2MR.
and R37	JRI0223030	Composition: 30,000 ohms ±5%, 1/4 w.	R20	3R77P102J	Composition: 1000 ohms ±5%, 1/2 w.
R38	3R152P103J	Composition: 10,000 ohms ±5%, 1/4 w.	R21	3R77P203J	Composition: 20,000 ohms ±5%, 1/2 w.
			R22	3R77P113J	Composition: 11,000 ohms ±5%, 1/2 w.
XFL1	7768887P17	Tibo phone 7 pings of the Flor 04 710 00	R23	3R77P361J	Composition: 360 ohms ±5%, 1/2 w.
	110000711	Tube, phen: 7 pins; sim to Elco 04-710-02.	R24	3R77P242J	Composition: 2400 ohms ±5%, 1/2 w.
		IN MODELS EARLIER THAN REV A	R25 R26	3R77P152J 3R77P201J	Composition: 1500 ohms ±5%, 1/2 w. Composition: 200 ohms ±5%, 1/2 w.
		COMPONENT BOARD	R27	3R77P513J	Composition: 51,000 ohms ±5%, 1/2 w.
		19C303864G1	R28	3R77P242J	Composition: 2400 ohms ±5%, 1/2 w.
		CAPACITORS	R29	3R77P203J	Composition: 20,000 ohms ±5%, 1/2 w.
C1	19B209243P9	Polyester: 0.22 μf ±20%, 50 VDCW.	R30	3R77P512J	Composition: 5100 ohms ±5%, 1/2 w.
C2	5496267P2	Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague Type 150D.	R31	3R77P272J	Composition: 2700 ohms ±5%, 1/2 w.
C3 and	5496267P14	Tantalum: 15 μf ±20%, 20 VDCW; sim to Sprague Type 150D,	R32	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.
C4			R33 R34	3R77P182J 3R77P512J	Composition: 1800 ohms ±5%, 1/2 w. Composition: 5100 ohms ±5%, 1/2 w.
CR1	5494922P1	DIODES AND RECTIFIERS			·
and CR2	010102221	Silicon, Sim to Type 18450.	XFL1	7768887P17	SOCKETS
CR3	4036936P1	Silicon.	AFLI	7700007277	Tube, phen: 7 pins; sim to Elco 04-710-02.
thru CR5					
		JACKS AND RECEPTACLES	FL1		TONE FREQUENCY NETWORK 19B205280
Jl thru	4033513P16	Contact, electrical: sim to Bead Chain R52-1.		19B205280G1 19B205280G2	71.9 Hz 77.0 Hz
J7				19B205280G3 19B205280G4	82.5 Hz 88.5 Hz
Q1	19A115362P1			19B205280G5 19B205280G6	94.8 Hz 100.0 Hz
and Q2				19B205280G7 19B205280G8 19B205280G9	103.5 Hz 107.2 Hz 110.9 Hz
Q3	19Al15123Pl	Silicon, NPN; sim to Type 2N2712.		19B205280G10 19B205280G11	114.8 Hz 118.8 Hz
Q4	19A115362P1	Silicon, NPN; sim to Type 2N2925.		19B205280G12 19B205280G13	123.0 Hz 127.3 Hz
Q5 thru	19A115123P1	Silicon, NPN; sim to Type 2N2712.		19B205280G14 19B205280G15 19B205280G16	131.8 Hz 136.5 Hz 141.3 Hz
Q7				19B205280G17 19B205280G18	146.2 Hz 151.4 Hz
		RESISTORS		19B205280G19 19B205280G20	156.7 Hz 162.2 Hz
Rl	5495948P426	Deposited carbon: 182,000 ohms ±1%, 1/2 w; sim to Texas Instrument Type CD1/2MR.		19B205280G21 19B205280G22 19B205280G23	167,9 Hz 173.8 Hz 179.9 Hz
R2	5495948P365	Deposited carbon: 46,400 ohms ±1%, 1/2 w; sim	1	19B205280G23 19B205280G24 19B205280G25	186.2 Hz 192.8 Hz
R3	5495948P389	to Texas Instrument Type CD1/2MR. Deposited carbon: 82,500 ohms ±1%, 1/2 w; sim to	1	19B205280G26 19B205280G30	203.5 Hz 74.4 Hz
, and	0100705000	Texas Instrument Type CD1/2MR.		19B205280G31 19B205280G32	7.97 Hz 85.4 Hz
R4	3R77P204J	Composition: 0.2 megohm ±5%, 1/2 w.	1	19B205280G33 19B205280G34	91.5 Hz 97.4 Hz
			1		
			1		

SYMBOL	GE PART NO.	DESCRIPTION
S1*	19B209040P7	Slide: SPDT, 0.5 amp at 125 v; sim to Continental-Wirt Type G-132. (Added by REV B).
W1		CABLE 19B205184G1
P1 and P2	4036634P2	
P4 thru P7	4036634P2	Contact, electrical: sim to AMP 42429-2.
P8		Includes the following:
	5491563P4	Shell, connector: sim to Methode C860-1V.
	5491563P2	Connector, phen: 9 pins; sim to Methode M860.

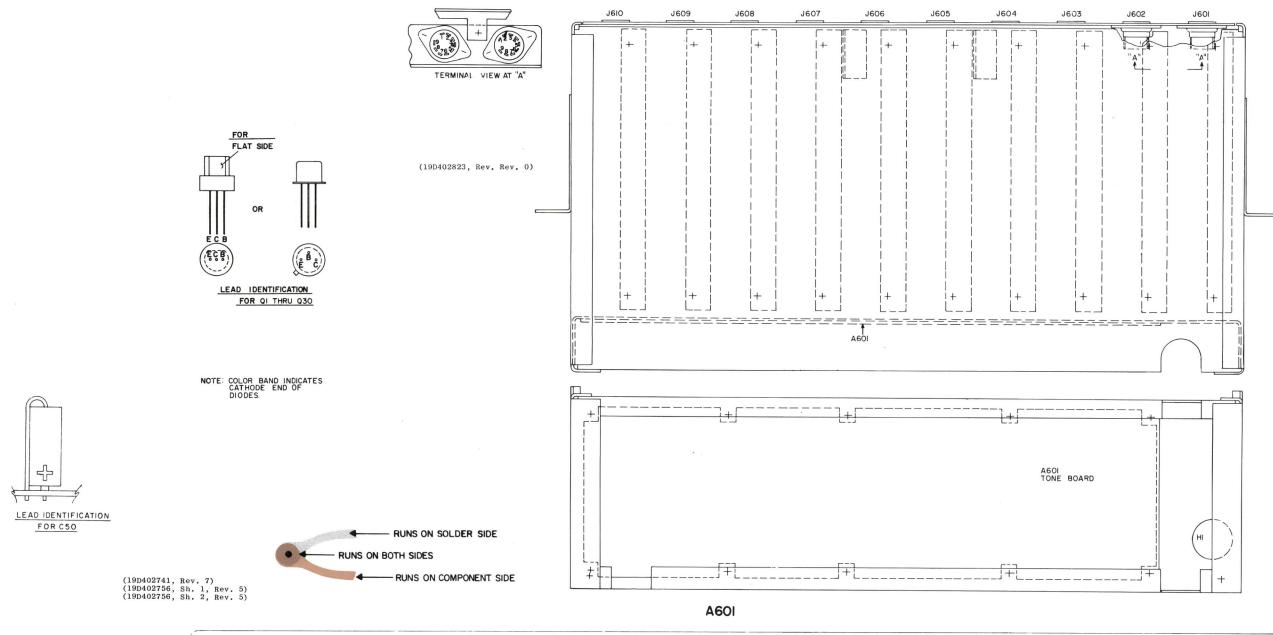
PRODUCTION CHANGES

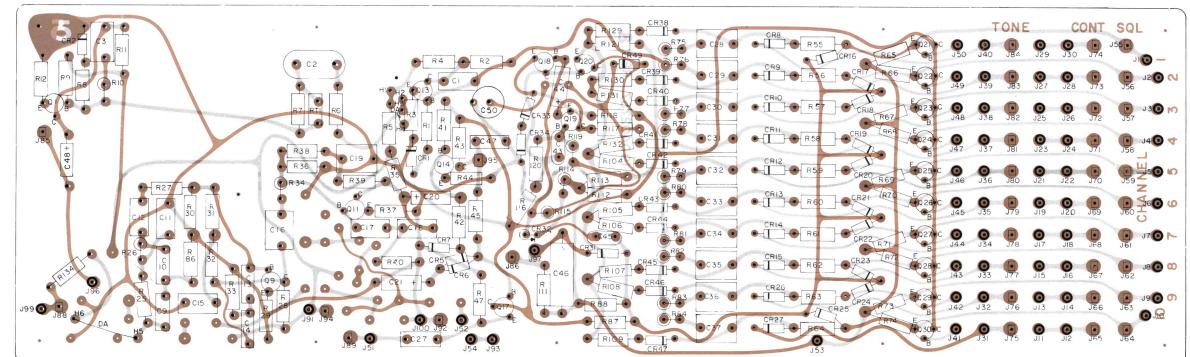
Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - To make Tone Module compatible with Shared Remote Equipment. Changed Component Board Al.

REV. B - To provide test switch. Added S1.

12



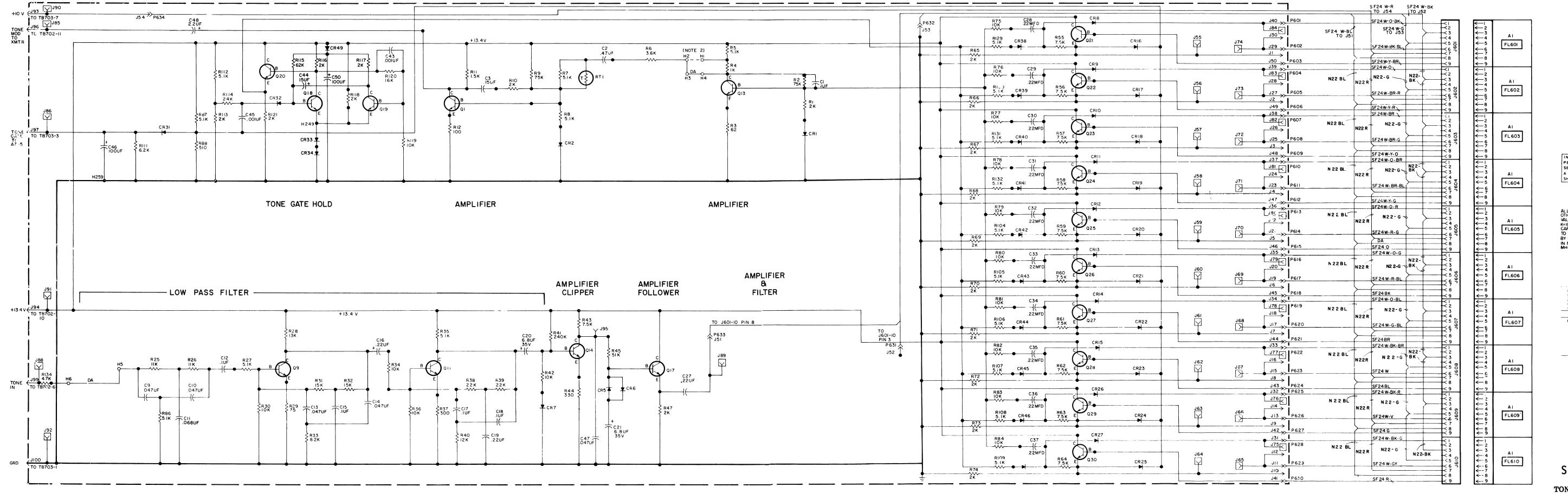


OUTLINE DIAGRAM

TONE PANEL 19D402486G1

14

Issue 6



BOARD, TONE PL19D402615G2

ALL CIRCUITS PRINTED WIRING EXCEPT WHERE OTHERWISE SHOWN.

2. IN SHARED REMOTE STATION APPLICATIONS, DA WIRE IS REMOVED FROM BETWEEN H3 AND H4 AND CONNECTED BETWEEN HI AND H2.

IN ORDER TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COMPONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

ALL RESISTORS ARE 1/2 WATT UNLESS OTHERWISE SPECIFIEL AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG=1,000,000 OHMS CAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF- MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MICLIHENRYS OR H=HENRYS

SEE APPLICABLE PRODUCTION CHANGE SHEETS IN INSTRUCTION BOOK SECTION DEALING WITH THIS UNIT, FOR DES-CRIPTION OF CHANGES UNDER EACH REVISION LETTER. THIS ELEM DIAG APPLIES TO MODEL NO REV LETTER 19D402**48**6GI

SCHEMATIC DIAGRAM

TONE PANEL 19D402486G1

LBI3699

PARTS LIST

TONE PANEL 19D402486G1

SYMBOL	GE PART NO.	DESCRIPTION
A601		TONE BOARD 19D402615G2
Cl	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.
C2*	19A116080P11	Polyester: 0.47 µf ±20%, 50 VDCW.
		In REV C and earlier:
	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW.
C3	19A116080P8	Polyester: 0.15 µf ±20%, 50 VDCW.
C8*	5496267P14	Tantalum: 15 μ f \pm 20%, 20 VDCW; sim to Sprague Type 150D. Deleted by REV B.
C9* and C10*	9A116080P205	Polyester: 0.047 µf ±5%, 50 VDCW.
		In Models of REV A and earlier:
63.3	19B209243P5	Polyester: .047 μf ±20%, 50 VDCW.
C11*	19A116080P206	Polyester: 0.068 μf ±5%, 50 VDCW.
		In REV B-D:
	19A116080P207	Polyester: 0.1 μf ±5%, 50 VDCW.
	1000004000	In Models of REV A and earlier:
C1.0	198209243P7	Polyester: 0.1 µf ±20%, 50 VDCW.
C12 C13*	19A116080P7 19A116080P205	Polyester: 0.1 µf ±20%, 50 VDCW.
and Cl4*	198110080P205	Polyester: .047 µf ±5%, 50 VDCW. In Models of REV A and earlier:
	19B209243P5	Polyester: 0.047 µf ±20%, 50 VDCW.
C15*	19A116080P207	Polyester: 0.1 µf ±5%, 50 VDCW.
	İ	In Models of REV A and earlier:
	19B209243P7	Polyester: 0.1 µf ±20%, 50 VDCW.
C16	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW.
C17* and C18*	19A116080P207	Polyester: 0.1 µf ±5%, 50 VDCW.
		In Models of REV A and earlier:
	19B209243P7	Polyester: 0.1 µf ±20%, 50 VDCW.
C19*	19A116080P109	Polyester: 0.22 μf ±10%, 50 VDCW.
	10000004000	In Models of REV A and earlier:
C20	19B209243P9 5496267P18	Polyester: 0.22 µf ±20%, 50 VDCW.
and C21	3496267P18	Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague Type 150D.
C22* and C23*	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW. Deleted by REV B.
C24* and C25*	7774750P5	Ceramic disc: 0.0015 μf +100% -0%, 500 VDCW. Deleted by REV B.
C26*	7774750P8	Ceramic disc: 0.0033 µf +100% -0%, 500 VDCW. Deleted by REV B.
C27 thru C37	19A116080P9	Polyester: 0.22 μf ±20%, 50 VDCW.
C43	774750P4	Ceramic disc: 0.001 µf +100% -0%, 500 VDCW.
C44	5496267P14	Tantalum: 15 μ f $\pm 20\%$, 20 VDCW; sim to Sprague Type 150D.
C45	7774750P4	Ceramic disc: 0.001 µf +100% -0%, 500 VDCW.
C46	5496267P16	Tantalum: 100 μf $\pm 20\%$, 20 VDCW; sim to Sprague Type 150D.
C47*	19A116080P5	Polyester: .047 µf ±20%, 50 VDCW. Added by REV
C48*	5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprague Type 150D.

CR1 and CR2 19All: CR5 thru CR27 CR31 thru CR34 CR38 thru CR47 CR49* 19All: 5 thru J55 thru J86 J88 403153 and J89 J91 403351 J92 403153 J93 403351 J94 and J95 J96 thru J101 CR47 CR47 CR47 CR47 CR47 CR47 CR47 CR47	1116080P9 1115680P107 1115250P1 115250P1 115250P1 115250P1	Polyester: 0.22 µf ±20%, 50 VDCW. Added by REV A. Deleted by REV D. Electrolytic: 100 µf +150% -10%, 15 VDCW; sim to Mallory Type TTX. Added by REV C. DIODES AND RECTIFIERS	R24* R25* and R26* R27 R28 R29 R30 R31	3R77P201J 3R77P113J 3R77P103J 3R77P512J 3R77P133J 3R77P750J	Composition: 200 ohms ±5%, 1/2 w. Deleted b REV B. Composition: 11K ohms ±5%, 1/2 w. In Models of REV A or earlier: Composition: 10,000 ohms ±5%, 1/2 w. Composition: 5.1K ohms ±5%, 1/2 w. Composition: 13K ohms ±5%, 1/2 w.
CR1 and CR2 CR5 19A115 thru CR27 CR31 thru CR34 19A115 thru J54 403153 and J89 J91 403351 J92 403153 J93 403351 J94 and J95 thru J101 403351 J96 thru J101 403351 J96 thru J101 403351 J97 403153 J98 403153 J98 403153 J98 403153 J99 J91 50	.115250P1 115250P1 115250P1 115250P1	to mallory Type TTX. Added by REV C. DIODES AND RECTIFIERS Silicon. Silicon.	and R26* R27 R28 R29 R30	3R77P103J 3R77P512J 3R77P133J	In Models of REV A or earlier: Composition: 10,000 ohms ±5%, 1/2 w. Composition: 5.1K ohms ±5%, 1/2 w.
CR2 CR3 CR31 thru CR34 CR38 thru CR34 CR38 thru CR47 CR49* 19A115 J1 403351 J55 thru J56 403153 J88 and J89 J91 403351 J92 403153 J93 403351 J94 403153 J95 J96 thru J101 Q1 19A115 Q1 Q1 19A115 Q1 Q1 19A115 Q1 Q1 19A115 Q1 Q1 Q1 19A115 Q1	115250P1 115250P1 115250P1 115250P1	Silicon. Silicon.	R28 R29 R30	3R77P512J 3R77P133J	Composition: 10,000 ohms ±5%, 1/2 w. Composition: 5.1K ohms ±5%, 1/2 w.
CR2 CR3 CR31 thru CR34 CR38 thru CR34 CR38 thru CR47 CR49* 19A115 J1 403351 J55 thru J56 403153 J88 and J89 J91 403351 J92 403153 J93 403351 J94 403153 J95 J96 thru J101 Q1 19A115 Q1 Q1 19A115 Q1 Q1 19A115 Q1 Q1 19A115 Q1 Q1 Q1 19A115 Q1	115250P1 115250P1 115250P1 115250P1	Silicon.	R28 R29 R30	3R77P512J 3R77P133J	Composition: 5.1K ohms ±5%, 1/2 w.
CR2 CR5 thru CR27 CR31 thru CR34 CR38 thru CR47 CR49* 19A115 thru J54 403153 thru J86 J88 403153 and J89 J91 403351 J92 403153 J93 403351 J94 403153 J93 403351 J94 403153 J95 thru J101 Q1 19A115 Q1 19A11	115250P1 115250P1 115250P1	Silicon.	R28 R29 R30	3R77P133J	· ·
CR27 CR31 CR31 IPALIS Thru CR34 CR38 thru CR47 CR49* J55 thru J54 J55 thru J54 J88 and J89 J91 403351 J92 403153 J93 403351 J94 and J99 I9A153 J95 LTru J90 IPALIS Q1 IPALIS	115250P1 115250P1 115250P1	Silicon.	R29 R30	1	composition: 13k onms 15%, 1/2 w.
CR31 thru CR34 CR38 thru CR47 CR49* 19A115 J1 thru J54 J55 403153 thru J56 J88 and J89 J91 403351 J92 403153 J93 403351 J94 403153 J95 J96 thru J101 Q1 19A115 Q1 Q1 19A115 Q1 Q1 19A115 Q1	115250P1 115250P1		l l	1	Composition: 75 ohms ±5%, 1/2 w.
CR34 CR34 CR34 CR38 thru CR47 CR49* J1	115250P1 115250P1		R31	3R77P103J	Composition: 10K ohms ±5%, 1/2 w.
thru CR47 CR49* 19A115 J1 thru J54 J55 403153 thru J86 J88 403153 and J89 J91 403351 J92 403153 J93 403351 J94 403153 J95 thru J101 Q1 19A115 Q1	115250P1	Silicon.	and R32	3R77P153J	Composition: 15K ohms ±5%, 1/2 w.
CR49* 19A115 J1 thru J55 thru J86 J88 403153 J89 403351 J91 403351 J92 403153 J93 403351 J94 403153 J95 403153 J96 thru J101 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 R1 3R77P20 R2 3R77P78 R3 3R77P5 R6 3R77P5 R6 3R77P5 R7 and R8 R9 3R77P78			R33	3R77P822J	Composition: 8.2K ohms ±5%, 1/2 w.
J1 thru J54 J55 thru J86 J88 and J89 J91 403351 J92 403153 J93 403351 J94 403153 J95 J96 thru J101 Q1 19A115 Q1 19A1			R34	3R77P103J	Composition: 10K ohms ±5%, 1/2 w.
thru J54 J55 J55 J88 J88 J88 J91 J91 J92 J91 J92 J93 J93 J93 J93 J94 J95 J94 J95 J96 J91 J96 J97	351 3 P4	Silicon. Added by REV C.	R35	3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.
thru J54 J55 J55 J88 J88 J88 J91 J91 J92 J91 J92 J93 J93 J93 J93 J94 J95 J94 J95 J96 J91 J96 J97	3513P4	JACKS AND RECEPTACLES	R36	3R77P103J	Composition: 10K ohms ±5%, 1/2 w.
J54 J55 thru J86 J88 and J89 J91 403153 J92 403153 J93 403351 J94 403153 J95 J96 thru J101 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 Q1		Contact, electrical: sim to Bead Chain L93-3.	R37	3R77P301J	Composition: 300 ohms ±5%, 1/2 w.
J86 J88 and J89 J91 403153 J92 403153 J92 403153 J93 403351 J94 403351 J95 J96 thru J101 Q1 19A115 Q4* 19A115 Q10* 19A115 Q11 19A115 Q13 and Q14 Q17 thru Q30 R1 3R77P20 R2 3R77P75 R6 3R77P51 R6 3R77P51 R8 R9 3R77P75	1537P1	Terminal: sim to Alden Products 654T.	R38 and R39	3R77P223J	Composition: 22K ohms ±5%, 1/2 w.
and J89 J91 403351 J92 403153 J93 403351 J94 403351 J95 403351 J96 thru J901 Q1 19A115 Q9 19A115 Q10 19A115 Q11 19A115 Q13 and J9A115 Q14 19A115 R1 3R77P20 R1 3R77P20 R2 3R77P75 R3 3R77P51 R6 3R77P51 R6 3R77P51 R7 and R8 R9 3R77P75			R40	3R77P123J	Composition: 12K ohms ±5%, 1/2 w.
J89 J91 J92 J93 J92 J93 J93 J93 J94 J95 J96 Hru J101 Q1 19A115 Q4* 19A115 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 Q1 19A115 R1 3R77P20 R2 3R77P3 R3 3R77P5 R6 3R77P5 R7 and R8 R9 3R77P5	1537P1	Terminal: sim to Alden Products 654T.	R41	3R77P244J	Composition: 240K ohms ±5%, 1/2 w.
J92 403153 J93 403351 J94 403153 and J95 403351 J96 403351 J96 403351 J101 19A115 Q1 19A115 Q10* 19A115 Q11 19A115 Q13 19A115 Q14 19A115 Q17 thru Q30 19A115 R1 3R77P20 R2 3R77P78 R3 3R77P6 R4 3R77P1 R5 3R77P5 R6 3R77P5 R6 3R77P5 R7 and R8 R9 3R77P78			R42	3R77P103J	Composition: 10K ohms ±5%, 1/2 w.
J93 403351 J94 and J95 J96 thru J101 Q1 19A115 Q4* 19A115 Q10* 19A115 Q11 19A115 Q13 19A115 Q14 19A115 R1 3R77P20 R2 3R77P78 R3 3R77P5 R6 3R77P5 R6 3R77P5 R7 and R8 R9 3R77P75	3513P4	Contact, electrical: sim to Bead Chain L93-3.	R43	3R77P752J	Composition: 7.5K ohms ±5%, 1/2 w.
J94 and J95 J96 thru J101 Q1		Terminal: sim to Alden Products 654T.	R44	3R77P331J	Composition: 330 ohms ±5%, 1/2 w.
and J95	3513P4	Contact, electrical: sim to Bead Chain L93-3.	R45	3R77P513J	Composition: 51K ohms ±5%, 1/2 w.
J96 thru J101 Q1	1537P1	Terminal: sim to Alden Products 654T.	R47	3R77P202J	Composition: 2K ohms ±5%, 1/2 w.
thru J101 Q1 19A115 Q4* 19A115 Q9 19A115 Q10* 19A115 Q11 19A115 Q13 19A115 Q14 Q17 thru Q30 R1 3R77P20 R2 3R77P78 R3 3R77P61 R6 3R77P51 R6 3R77P51 R7 and R8 R9 3R77P78			R48*	3R77P202J	Composition: 2K ohms ±5%, 1/2 w. Deleted by REV B.
Q4* 19A115: Q9 19A115: Q10* 19A115: Q11 19A115: Q13 and Q14 Q17 thru Q30 R1 3R77P20 R2 3R77P75: R4 3R77P10 R5 3R77P51 R6 3R77P51 R7 and R8 R9 3R77P75	3513P4	Contact, electrical: sim to Bead Chain L93-3.	R49* and R59*	3R77P512J	Composition: 5.1K ohms $\pm 5\%$, $1/2$ w. Deleted by REV B.
Q4* 19A115: Q9 19A115: Q10* 19A115: Q11 19A115: Q13 and Q14 Q17 thru Q30 R1 3R77P20 R2 3R77P75: R4 3R77P10 R5 3R77P51 R6 3R77P51 R7 and R8 R9 3R77P75		TRANSISTORS	R51*	3R77P200J	Composition: 20 ohms $\pm 5\%$, $1/2$ w. Deleted by
Q9 19A115: Q10* 19A115: Q11 19A115: Q13 19A115: and Q14 19A115: Thru Q30 19A115: R1 3R77P20 R2 3R77P75 R3 3R77P61 R5 3R77P51 R6 3R77P51 R7 and R8 R9 3R77P75	.15123P1	Silicon, NPN.			REV B.
Q10* 19A115: Q11 19A115: and Q14 19A115: q13 and Q14 19A115: q14 19A115: q15 and Q30		Silicon, NPN. Deleted by REV B.	R52* and	3R77P153J	Composition: 15K ohms ±5%, 1/2 w. Deleted by REV B.
Q11 19A115: Q13 and Q14 2017 thru Q30 19A115: R1 3R77P20 R2 3R77P75 R4 3R77P10 R5 3R77P51 R6 3R77P51 And R8 R9 3R77P75		Silicon, NPN. Silicon, NPN. Deleted by REV B.	R53*	3R77P682J	Composition C OV shap to 1/0 m Political
Q13 and Q14 19A115: And Q17 thru Q30 19A115: And Q30 R1 3R77P20 R2 3R77P30 R4 3R77P30 R6 3R77P30 R7 and R8 R9 3R77P75		Silicon, NPN.	R54.*	3R77P082J	Composition: 6.8K ohms ±5%, 1/2 w. Deleted by REV B.
Q17 thru Q30 R1	15123P1	Silicon, NPN.	R55 thru R64	3R77P752J	Composition: 7.5K ohms ±5%, 1/2 w.
R1 3R77P20 R2 3R77P75 R3 3R77P61 R5 3R77P51 R6 3R77P51 R7 and R8 R9 3R77P75	15123P1	Silicon, NPN.	R65 thru R74	3R77P202J	Composition: 2K ohms ±5%, 1/2 w.
R2 3R77P75 R3 3R77P62 R4 3R77P10 R5 3R77P53 R6 3R77P53 R7 and R8 R9 3R77P75		RESISTORS	R75 thru R84	3R77P103J	Composition: 10K ohms ±5%, 1/2 w.
R3 3R77P62 R4 3R77P10 R5 3R77P51 R6 3R77P52 R7 and R8 R9 3R77P75		Composition: 2K ohms ±5%, 1/2 w.	R86*	3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.
R4 3R77P10 R5 3R77P51 R6 3R77P30 R7 3R77P51 and R8 R9 3R77P75		Composition: 75% ohms ±5%, 1/2 w.			In Models of REV A and earlier:
R5 3R77P51 R6 3R77P51 R7 3R77P51 R8 3R77P75		Composition: 62 ohms ±5%, 1/2 w.	1	3R77P472J	Composition: 4.7K ohms ±5%, 1/2 w.
R6 3R77P36 R7 3R77P51 and R8 R9 3R77P75		Composition: 1K ohms ±5%, 1/2 w.	R87	3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.
R7 3R77P51 and R8 3R77P75		Composition: 5.1K ohms ±5%, 1/2 w.	R88	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.
R9 3R77P75		Composition: 3.6K ohms ±5%, 1/2 w. Composition: 5.1K ohms ±5%, 1/2 w.	R104 thru R109	3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.
l.	PG5.03		R111	3R77P622J	Composition: 6.2K ohms ±5%, 1/2 w.
3K//P20	ł	Composition: 75K ohms ±5%, 1/2 w.	R112	3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.
R11 3R77P15		Composition: 2K ohms ±5%, 1/2 w. Composition: 1.5K ohms ±5%, 1/2 w.	R113*	3R77P202J	Composition: 2K ohms ±5%, 1/2 w.
R12 3R77P10	i	Composition: 1.5% onms ±5%, 1/2 w.			In REV and earlier:
R20* 3R77P27		Composition: 2.7K ohms ±5%, 1/2 w. Deleted		3R77P102J	Composition: 1K ohms ±5%, 1/2 w.
ļ		by REV B.	R114	3R77P243J	Composition: 24K ohms ±5%, 1/2 w.
R21* 3R77P36	D2621	Composition: 36K ohms $\pm 5\%$, $1/2$ w. Deleted by REV B.	R115 R116	3R77P623J 3R77P202J	Composition: 62K ohms ±5%, 1/2 w. Composition: 2K ohms ±5%, 1/2 w.
R22* 3R77P10		Composition: 1K ohms ±5%, 1/2 w. Deleted by REV B. Composition: 510 ohms ±5%, 1/2 w. Deleted by	thru R118		

	19B209243P7	Polyester: 0.1 \(\mu f \pm 20\% \), 50 VDCW.			i	1 1	1	1
C16	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW.	Q10*	19A115123P1	Silicon, NPN. Deleted by REV B.	R54*	3R77P682J	Composition: 6.8K ohm
C17*	19A116080P207	Polyester: 0.1 µf ±5%, 50 VDCW.	Q11	19A115123P1	Silicon, NPN.	R55	3R77P752J	Composition: 7.5K ohm
and C18*		, , , , , , , , , , , , , , , , , , , ,	Q13 and	19A115123P1	Silicon, NPN.	thru R64	J. T. T. T. D. Z.	Composition: V.or olim
	ĺ	In Models of REV A and earlier:	Q14		·	R65	3R77P202J	Composition: 2K ohms
	19B209243P7	Polyester: 0.1 µf ±20%, 50 VDCW.	Q17 thru	19A115123P1	Silicon, NPN.	thru R74	SR11P2025	Composition: 2k onms
C19*	19A116080P109	Polyester: 0.22 µf ±10%, 50 VDCW.	Q30	ĺ		R74	3R77P103J	Composition. 10% shap
		In Models of REV A and earlier:			RESISTORS	thru	387791033	Composition: 10K ohms
	19B209243P9	Polyester: 0.22 μf ±20%, 50 VDCW.	R1	3R77P202J	Composition: 2K ohms ±5%, 1/2 w.	R84	onggres 102	
C20 and	5496267P18	Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague Type 150D.	R2	3R77P753J	Composition: 75K ohms ±5%, 1/2 w.	R86*	3R77P512J	Composition: 5.1K ohm
C21		sprague Type 130D.	R3	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.			In Models of REV A and
C22* and	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW. Deleted by	R4	3R77P102J	Composition: 1K ohms ±5%, 1/2 w.		3R77P472J	Composition: 4.7K ohm
C23*		REV B.	R5	3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.	R87	3R77P512J	Composition: 5.1K ohm
C24*	7774750P5	Ceramic disc: 0.0015 µf +100% -0%, 500 VDCW.	R6	3R77P362J	Composition: 3.6K ohms ±5%, 1/2 w.	R88	3R77P511J	Composition: 510 ohms
and C25*		Deleted by REV B.	R7	3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.	R104 thru	3R77P512J	Composition: 5.1K ohm
C26*	7774750P8	Ceramic disc: 0.0033 µf +100% -0%, 500 VDCW.	and R8			R109		
	J.,	Deleted by REV B.	R9	3R77P753J	Composition: 75K ohms ±5%, 1/2 w.	R111	3R77P622J	Composition: 6.2K ohm
C27 thru	19A116080P9	Polyester: 0.22 μf ±20%, 50 VDCW.	R10	3R77P202J	Composition: 2K ohms ±5%, 1/2 w.	R112	3R77P512J	Composition: 5.1K ohm
C37	ł		R11	3R77P152J	Composition: 1.5K ohms ±5%, 1/2 w.	R113*	3R77P202J	Composition: 2K ohms
C43	774750P4	Ceramic disc: 0.001 μf +100% -0%, 500 VDCW.	R12	3R77P101J	Composition: 100 ohms ±5%, 1/2 w.			In REV and earlier:
C44	5496267P14	Tantalum: 15 μ f $\pm 20\%$, 20 VDCW; sim to Sprague Type 150D.	R20*	3R77P272J	Composition: 2.7K ohms ±5%, 1/2 w. Deleted		3R77P102J	Composition: 1K ohms
C45	7774750P4	Ceramic disc: 0.001 µf +100% -0%, 500 VDCW.		ļ	by REV B.	R114	3R77P243J	Composition: 24K ohms
C46	5496267P16	Tantalum: 100 µf ±20%, 20 VDCW; sim to Sprague	R21*	3R77P363J	Composition: 36K ohms $\pm 5\%$, $1/2$ w. Deleted by REV B.	R115	3R77P623J	Composition: 62K ohms
		Type 150D,	R22*	3R77P102J	Composition: 1K ohms ±5%, 1/2 w. Deleted	R116 thru	3R77P202J	Composition: 2K ohms
C47*	19A116080P5	Polyester: .047 µf ±20%, 50 VDCW. Added by REV A.	1		by REV B.	R118		
C48*	5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprague Type 150D.	R23*	3R77P511J	Composition: 510 ohms $\pm 5\%$, $1/2$ w. Deleted by REV B.			
		In REV B and C:				i i		
	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW. Added by REV A.						ĺ
OMPON	ENTS ADDED, DE	LETED OR CHANGED BY PRODUCTION CHANGES						

16 +COMF

GE PART NO.	DESCRIPTION
397701021	Compatibility
	Composition: 10K ohms ±5%, 1/2 w.
	Composition: 16K ohms ±5%, 1/2 w.
	Composition: 2K ohms ±5%, 1/2 w.
3R77P512J	Composition: 5.1K ohms ±5%, 1/2 w.
3R77P472J	Composition: 4.7K ohms ±5%, 1/2 w.
	In Models of REV A and earlier:
3R77P101K	Composition: 100 ohms $\pm 10\%$, $1/2$ w. Added by REV A.
	THERM ISTORS
5490828P21	Rod: 1250 ohms ±10%, 0.38 w max; sim to Carborundum Type 492H-11.
	JACKS AND RECEPTACLES
7480532P11	Connector, tube, phen: 9 pins; sim to Elco 04-902-27.
4029840P2	Contact, electrical: sim to AMP 42827-2.
	MISCELLANEOUS
19D402486G2	Harness. (Includes J601-J610, P601-P634).
	,,
	3R77P101K 5490828P21 7480532P11 4029840P2

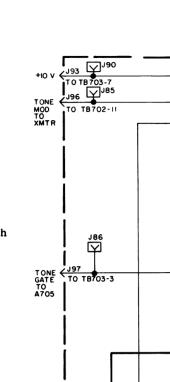
PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A To adjust input level and to improve attenuation of filter. Added C47-C49 and R134.
- REV. B To change response of bandpass filter to prevent voice blocking and faulting. Changed C9-C11, C13-C15, C17-C19, R25, R26, R86 and R134. Deleted C8, C22-C26, Q4, Q10, R20-R24 and R48-R54. Added jumper from R134 to junction of R25/C9.
- REV. C To eliminate a transmitted thumping noise when the transmitter is keyed in a community repeater application. Added C50 and CR49. Changed R113.
- REV. D To improve modulation level over the frequency range. Changed C2 and C48. Deleted C49
- REV. E To improve frequency response at 210 Hz. Changed Cll.

MODIFICATIONS:

- 1. Remove C2, C48 & C49.
- 2. Replace Cl (.luf) with .022uf capacitor.
- 3. Replace R2 (72,000 ohm) with 39,000 ohm resistor.
- 4. Replace R6 with 22µf capacitor.
- 5. Connect 5N 22-W wire as shown on printed board and schematic diagrams.
- 6. Shared Remote Stations Only Replace resistors R75-R84 (10,000 ohms) with 22,000 ohm resistors.



REMOVE

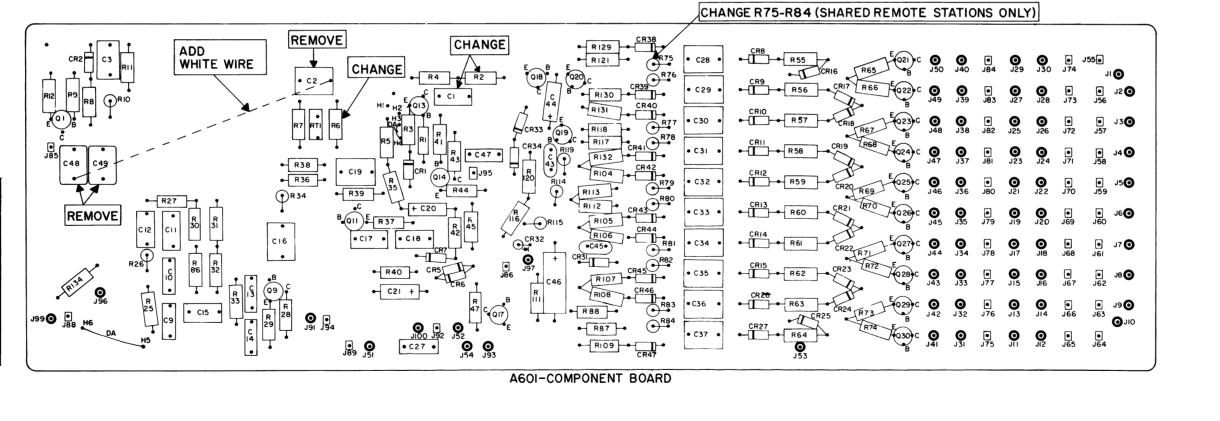
TONE GATE HOLD

WHITE WIRE

PARTS LIST

MODIFICATION KIT 19B216215-G1

QUANTITY	GE PART NUMBER	DESCRIPTION
		CAPACITORS
1	19B209243-P103	Polyester: .022 µf ±10%, 40 VDCW.
1	5496267-P19	Tantalum: 22 μf $\pm 20\%$, 35 VDCW, sim to Sprague Type 150D.
		RESISTORS
1	3R77-P393K	Composition: 39,000 ohms $\pm 10\%$, $1/2$ w.
10	3R77-P223K	Composition: 22,000 ohms $\pm 10\%$, $1/2$ w.



AMPLIFIER

A601-PARTIAL SCHEMATIC DIAGRAM

REMOVE

REMOVE

AMPLIFIER

CHANGE R75-R84 (SHARED REMOTE STATIONS ONLY)

INSTALLATION INSTRUCTIONS

TONE PANEL MODIFICATION KIT 19B216215G1 (FOR USE WITH ICOM EQUIPPED TRANSMITTERS)

CHANGE

LBI-3699

ORDERING SERVICE PARTS

Each component appearing on the schematic diagram is identified by a symbol number, to simplify locating it in the parts list. Each component is listed by symbol number, followed by its description and GE Part Number.

Service parts may be obtained from Authorized GE Communication Equipment Service Stations or through any GE Radio Communication Equipment Sales Office. When ordering a part, be sure to give:

- 1. GE Part Number for component
- Description of part
 Model number of equit Model number of equipment
- 4. Revision letter stamped on unit

These instructions do not purport to cover all details or variations in equipment nor to provide for every possible contingency to be met in connection with installation, operation or maintenance.

Should further information be desired, or should particular problems arise which are not covered sufficiently for the purchaser's purposes, contact the nearest Radio Communication Equipment Sales Office of the General Electric Company.

LBI-3699

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY ● LYNCHBURG, VIRGINIA 24502

